NSN 5961-01-369-9632 Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Function For Which Designed:
Rectifier
Mounting Method:
Terminal
Features Provided:
Electrostatic sensitive
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
2.2 forward voltage, peak and 0.1 gate trigger voltage, dc and 1.0 gate trigger voltage, dc
Test Data Document:
30063-a3086564 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0